

View Online at <https://aerobasegroup.com/nsn/5980-01-218-4234>

**General Description:**

Temp m55 to p125 degrees celcius; gallium arsenide infrared emitting diode, npn silicon phototransistor, hermetically sealed; 0.370 in.

Maximum dia; 0.185 in. Maximum h; 0.600 in. Maximum terminal lg

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

No

**Fiig:**

A23900